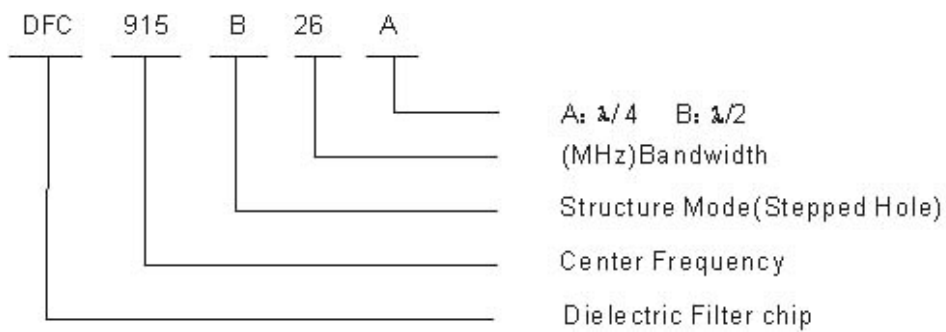


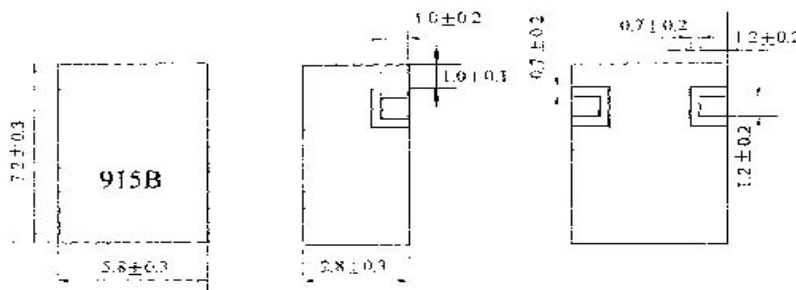
● INTRODUCTION

Microwave Dielectric Duplexer filter series is designed to be used RF transmitter and receiving with low insertion loss and higher attenuation and chip design , which could simplify your complex tuning and circuit design..

● Part Number



● Dimension (Unit:mm)



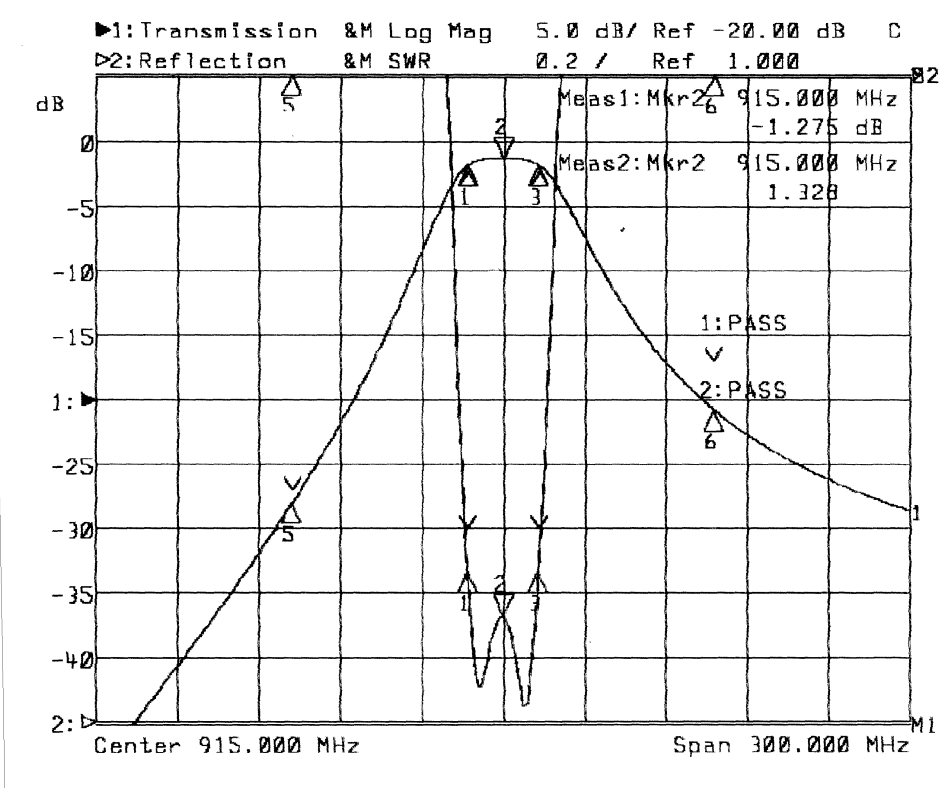
● Construction and Materials

No.	Part Name	Construction and materials
4.1	Filter	Dielectric materials
4.2	Number of pole	2 pole
4.3	In/output Terminals	Ag Plated
4.4	Ground Base	Ag Plated

● Electrical Characteristics

No.	Item	Specifications	Post Environmental orig Reading
5.1	Center frequency (fo)	915-/+1.5MHz	-/+1.5MHz
5.2	Insertion loss	2.5dB	-/+0.5 dB
5.3	Band width	fo-/+13.0MHz	-/+0.5MHz
5.4	Ripple(in BW)	0.5 dB Max.	-/+0.5 dB
5.5	V.S.W.R(in BW)	2.0 Max.	-/+0.5
5.6	Attenuation (Absolute value)	17dBmin (fo+77.5MHz) 27dBmin (fo-77.5MHz)	-/+2 dB
5.7	Permissible Input power	1 Watt	---
5.8	In/output impedance	50	---

● Characteristic curve



- **Environmental specifications**

Post Environmental Orig reading see to the table 2

Temperature range	25-/+3 °C
Humidity range	55~75%RH
Operating Temperature range	-10 °C ~+70 °C
Storage Temperature range	-25 °C ~+85 °C

- **Moisture Proof**

The device should satisfy the electrical characteristics specified in paragraph 5.1~5.6 after exposed to the temperature 40-/+2 °C and the humidity 90~95% RH for 96 hours. And leave it in a stationary state for 1 to 2 hours.

- **Vibration**

The device should satisfy the electrical characteristics specified in paragraph 5.1~5.6 after applied to the vibration of 10 to 55Hz with amplitude of 1.5mm for 2 hours each for of X,Y and Z directions.

- **Drop Shock**

The device should satisfy the electrical characteristics specified in paragraph 5.1~5.6 after dropped onto the hard wooden board from the height of 30cm for 3 times toward each X.Y and Z directions expect the terminal direction.

- **Heat Proof**

The device should satisfy the electrical characteristics specified in paragraph 5.1~5.6 after exposed to temperature 80-/+5 °C for 24-/+2 hours and leave it in a stationary state for 1 to 2 hours.

- **Temperature impact Resistance**

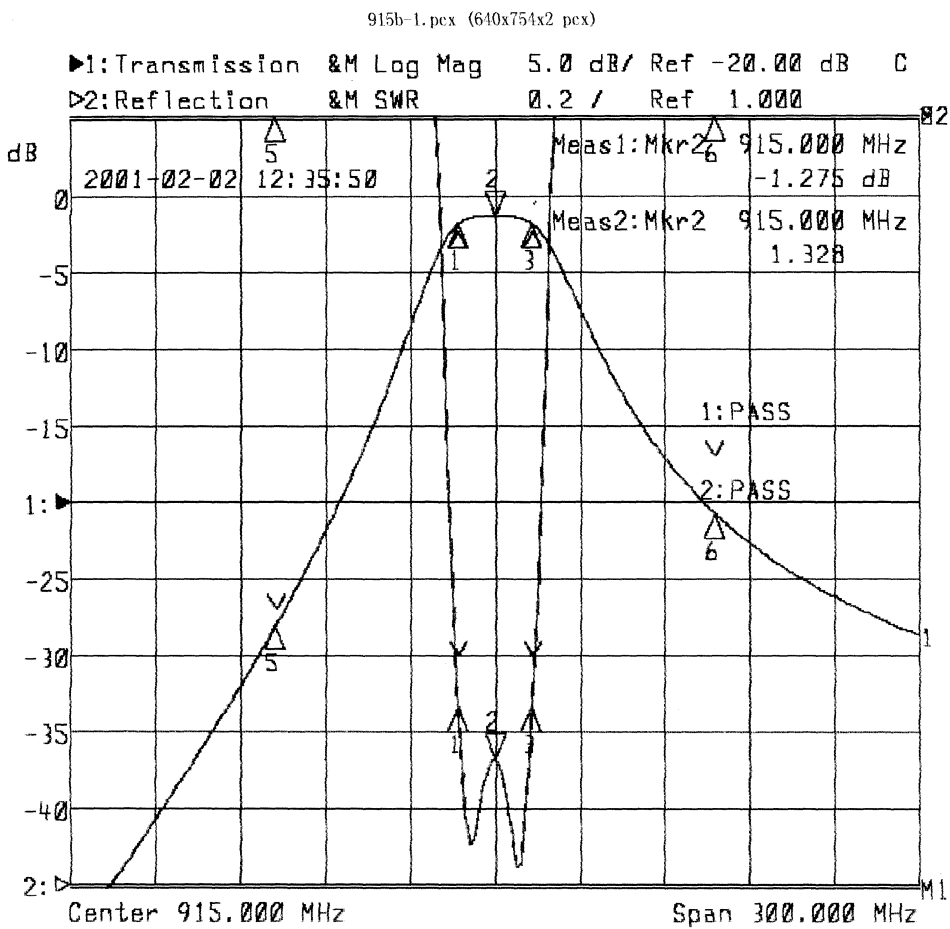
The device should satisfy the electrical characteristics specified in paragraph 5.1~5.6 after exposed to the low temperature -25 °C and high temperature +85 °C for 30-/+2 min each by 5 cycles and leave it in a stationary state for 1 to 2 hours.

● Solder Heat Proof

The device should be satisfied for preheated at 120°C ~150°C hold for 60 seconds and reflowed at 260°C +10°C for 10-/+0.5 seconds.

● Tensile Strength of Terminal

The device should not be broken after tensile force of 1.0kg is slowly applied to pull a lead pin of the fixed device in the lead axis direction for 10-/+1 seconds.



1: Mkr (MHz)	dB	2: Mkr (MHz)	
1: 902.00	-1.755	1: 902.00	1.464
2: 915.00	-1.275	2: 915.00	1.328
3: 928.00	-1.744	3: 928.00	1.463
5: 837.50	-28.002	5: 837.50	15.970
6: 992.50	-20.695	6: 992.50	15.366